

View Online at <https://aerobasegroup.com/nsn/5962-01-460-8347>

Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Temperature Range:

-55.0/+125.0 degrees celsius

Storage Temperature Range:

-65.0/+150.0 degrees celsius

End Application:

Sdv mod1 nav e/i fscm 0cjc4

Features Provided:

Monolithic and gated output and inverted output

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Metal oxide-semiconductor logic

Design Function And Quantity:

1 gate, or-nand

Terminal Surface Treatment:

Solder

Product Name:

Hex gate

Voltage Rating And Type Per Characteristic:

-0.5 volts input and 0.5 volts input

Special Features:

8a mosp-channel and n-channel enhancement mode device in a single monolithic structure; mos-logic gates are used primarily where low power dissipation and/or high noise immunity is needed; chip contains four inverters, one nor gate and one nand gate

Terminal Type And Quantity:

16 gullwing

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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